

# RJE0616JSP

-60V, -4A Silicon P Channel Thermal FET Power Switching

R07DS1234EJ0200

(Previous: REJ03G1944-0100)

Rev.2.00 Oct 27, 2014

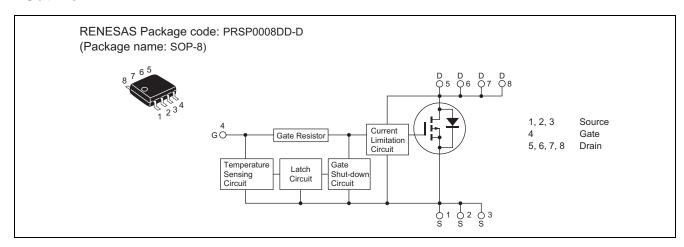
## **Description**

This FET has the over temperature shut-down capability sensing to the junction temperature. This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc..

#### **Features**

- For Automotive applications
- Built-in the over temperature shut-down circuit.
- High endurance capability against to the short circuit.
- Latch type shut down operation (need 0 voltage recovery).
- Built-in the current limitation circuit.
- Low on-resistance  $R_{DS(on)}$ : 77 m $\Omega$  Typ, 90 m $\Omega$  Max ( $V_{GS} = -10 \text{ V}$ )
- High density mounting
- AEC-Q101 compliant

#### **Outline**



#### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{DSS}$	-60	V
Gate to source voltage	V <sub>GSS</sub>	-16	V
	V <sub>GSS</sub>	2.5	V
Drain current	I <sub>D</sub> Note3	-4	A
Body-drain diode reverse drain current	I <sub>DR</sub>	-4	A
Avalanche current	I <sub>AP</sub> Note 2	-4	A
Avalanche energy	E <sub>AR</sub> Note 2	68.6	mJ
Channel dissipation	Pch Note 1	2.5	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1 When using the glass epoxy board (FR4  $40 \times 40 \times 1.6$  mm), PW  $\leq 10$  s

- 2. Tch = 25°C, Rg  $\geq$  50  $\Omega$
- 3. It provides by the current limitation lower bound value.

# **Typical Operation Characteristics**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	V <sub>IH</sub>	-3.5	_	_	V	
	$V_{IL}$	_		-1.2	V	
Input current	I <sub>IH1</sub>	_	_	-100	μΑ	$Vi = -8 V, V_{DS} = 0$
(Gate non shut down)	I <sub>IH2</sub>	_	_	-50	μΑ	$Vi = -3.5 \text{ V}, V_{DS} = 0$
	I <sub>IL</sub>	_	_	-1	μΑ	$Vi = -1.2 \text{ V}, V_{DS} = 0$
Input current	I <sub>IH(sd)1</sub>	_	-0.8	_	mA	$Vi = -8 V, V_{DS} = 0$
(Gate shut down)	I <sub>IH(sd)2</sub>	_	-0.35	_	mA	$Vi = -3.5 \text{ V}, V_{DS} = 0$
Shut down temperature	Tsd	_	175	_	°C	Channel temperature (dv/dt V <sub>GS</sub> ≥ 500 V/ms)
Gate operation voltage	Vop	-3.5	_	-12	V	(474: 163 = 555 77115)
Drain current (Current limitation value)	I <sub>D limt</sub>	-4	_	_	А	$V_{GS} = -12 \text{ V}, V_{DS} = -10 \text{ V}^{\text{Note 4}}$

Notes; 4. Pulse test

## **Electrical Characteristics**

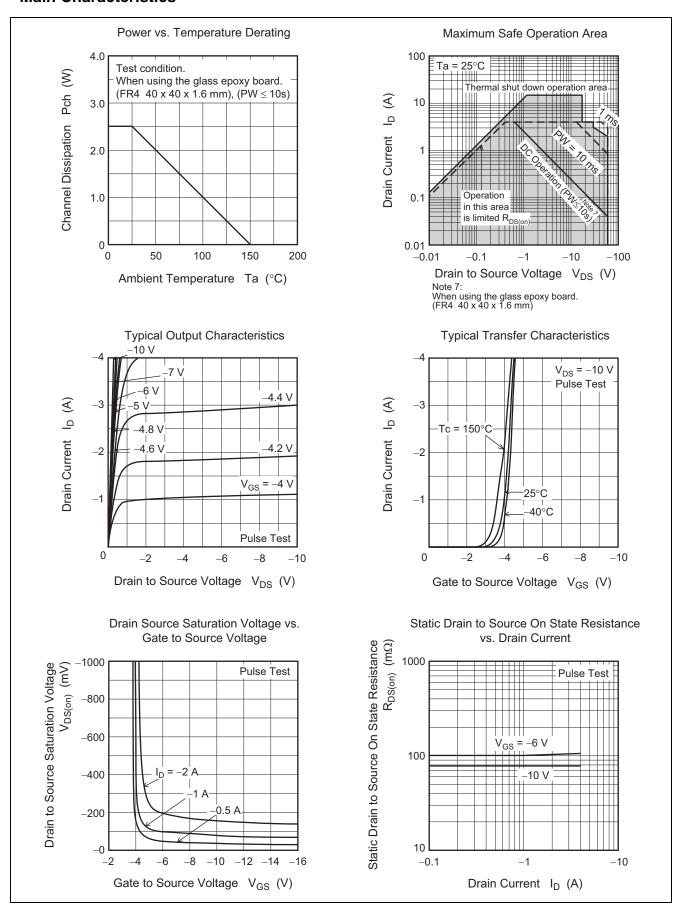
 $(Ta = 25^{\circ}C)$ 

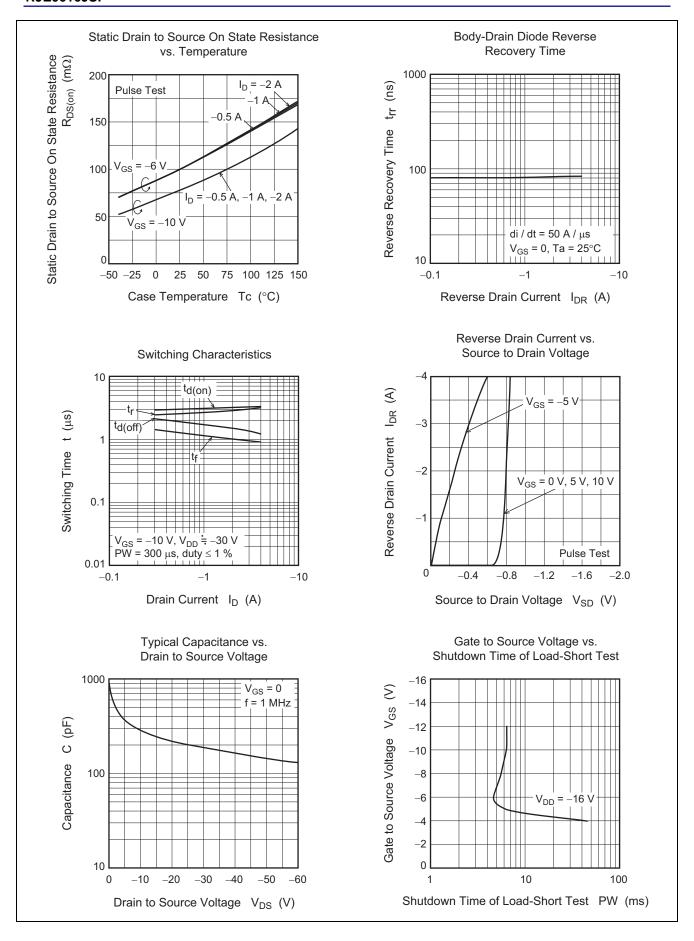
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	I <sub>D1</sub>		_	-4	Α	$V_{GS} = -3.5 \text{ V}, V_{DS} = -10 \text{ V}$
	I <sub>D2</sub>	-	_	-10	mA	$V_{GS} = -1.2 \text{ V}, V_{DS} = -10 \text{ V}$
	I <sub>D3</sub>	-4	_	_	Α	$V_{GS} = -12 \text{ V}, V_{DS} = -10 \text{ V}^{\text{Note 5}}$
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	-60	_	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown	$V_{(BR)GSS}$	-16	_	_	V	$I_G = -800 \mu\text{A},  V_{DS} = 0$
voltage	V <sub>(BR)GSS</sub>	2.5	_	_	V	$I_G = 100  \mu A,  V_{DS} = 0$
Gate to source leak current	I <sub>GSS1</sub>	_	_	-100	μΑ	$V_{GS} = -8 \text{ V}, V_{DS} = 0$
	I <sub>GSS2</sub>	_	_	-50	μΑ	$V_{GS} = -3.5 \text{ V}, V_{DS} = 0$
	I <sub>GSS3</sub>	_	_	-1	μΑ	$V_{GS} = -1.2 \text{ V}, V_{DS} = 0$
	I <sub>GSS4</sub>	_	_	100	μΑ	$V_{GS} = 2.4 \text{ V}, V_{DS} = 0$
Input current (shut down)	I <sub>GS(OP)1</sub>	_	-0.8	_	mA	$V_{GS} = -8 \text{ V}, V_{DS} = 0$
	I <sub>GS(OP)2</sub>	_	-0.35	_	mA	$V_{GS} = -3.5 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS1</sub>	-	_	-10	μΑ	$V_{DS} = -60 \text{ V}, V_{GS} = 0$
Zero gate voltage drain current	I <sub>DSS2</sub>	_	_	-10	μΑ	$V_{DS} = -48 \text{ V}, V_{GS} = 0,$ $Ta = 125^{\circ}\text{C}$
Gate to source cutoff voltage	V <sub>GS(off)</sub>	-2.2	_	-3.4	V	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$
Static drain to source on state	R <sub>DS(on)</sub>		102	150	mΩ	$I_D = -2 \text{ A}, V_{GS} = -6 \text{ V}^{\text{Note 5}}$
resistance	R <sub>DS(on)</sub>	-	77	90	mΩ	$I_D = -2 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note 5}}$
Output capacitance	Coss	_	290	_	pF	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{MHz}$
Turn-on delay time	t <sub>d(on)</sub>	_	3.20	_	μs	$V_{GS} = -10 \text{ V}, I_{D} = -2 \text{ A},$
Rise time	t <sub>r</sub>	_	2.80	_	μs	$R_L = 15 \Omega$
Turn-off delay time	t <sub>d(off)</sub>	_	1.55	_	μs	
Fall time	t <sub>f</sub>	_	1.05	_	μs	
Body-drain diode forward voltage	$V_{DF}$	_	-0.84	_	V	$I_F = -4 \text{ A}, V_{GS} = 0$
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	84	_	ns	$I_F = -4 \text{ A}, V_{GS} = 0$ $di_F/dt = 50 \text{ A}/\mu\text{s}$
Over load shut down operation time Note 6	t <sub>os1</sub>	_	6.34	_	ms	$V_{GS} = -5 \text{ V}, V_{DD} = -16 \text{ V}$

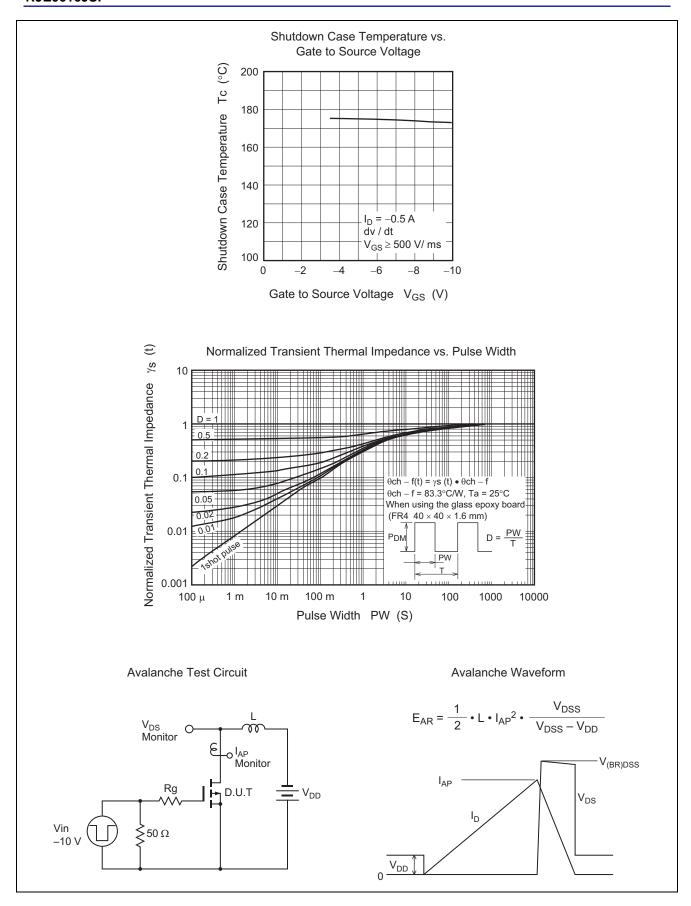
Notes: 5. Pulse test

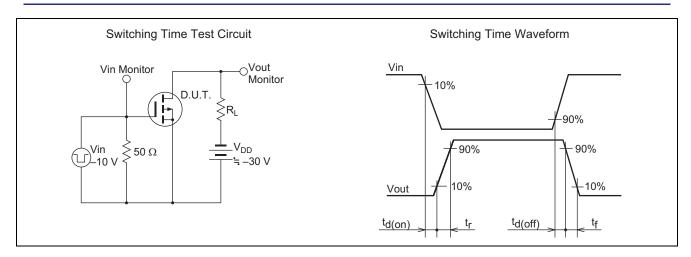
6. Including the junction temperature rise of the over loaded condition.

#### **Main Characteristics**

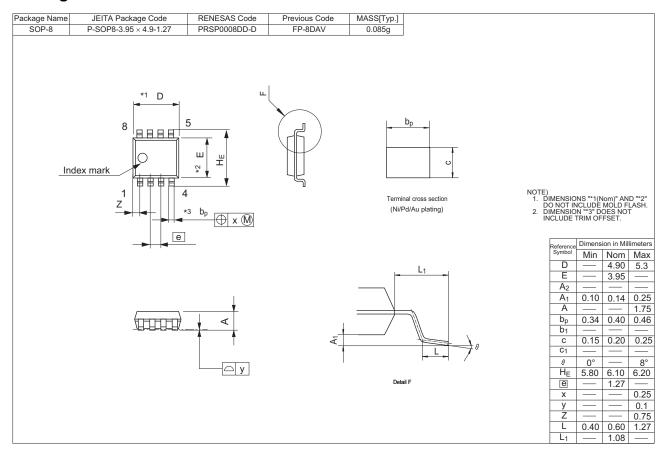








## **Package Dimensions**



## **Ordering Information**

Part No.	Quantity	Shipping Container
RJE0616JSP-00-J0	2500 pcs	Taping

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